# PNP small signal transistor **BC857B**

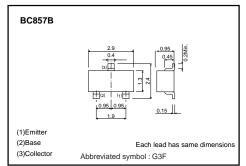
### ● Features

- 1) Ideal for switching and AF amplifier applications.
- 2) High current gain.

# Packaging specifications

Туре	Package	Taping
	Code	T116
	Basic ordering unit (pieces)	3000
BC857B		0

#### ●Dimensions (Unit: mm)



#### ● Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit	
Collector-base voltage	Vсво	-50	V	
Collector-emitter voltage	Vceo	-45	V	
Emitter-base voltage	Vево	-5	V	
Collector current	lc	-0.1	A	
Callester a succe discinction	D.	0.20	W	
Collector power dissipation	Pc	0.35	W *	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	-65 to 150	°C	

<sup>\*</sup> Mounted on a 7×5×0.6 mm CERAMIC SUBSTRATE

# ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-emitter breakdown voltage	BVceo	-45	-	-	V	Ic=-1mA
Collector-base breakdown voltage	ВУсво	-50	-	-	V	Ic= -50μA
Emitter-base breakdown voltage	ВУево	-5	-	-	V	Iε= -50μA
Collector-base cutoff current	Ісво	-	-	-0.015	μΑ	Vcb= -30V
Collector-emitter saturation voltage	VCE(sat1)	-	-	-0.3	V	Ic/I <sub>B</sub> = -10mA/ -0.5mA
	VCE(sat2)	-	-	-0.65	V	Ic/I <sub>B</sub> = -100mA/ -5mA
Base-emitter voltage	V <sub>BE(on)</sub>	-0.6	-	-0.75	V	Vce= -5V, Ic= -10mA
DC current transfer ratio	hfe	210	-	480	-	Vce= 5V, Ic= -2mA
Transition frequency	f⊤	-	250	-	MHz	Vc=-5V, I=20mA, f=100MHz
Collector outpu capacitance	Cob	-	-	4.5	pF	Vcb= -10V, f=1MHz
Collector-base cutoff current	Ісво	_	_	-4	μА	Vcb= -30V



#### **Notes**

- No technical content pages of this document may be reproduced in any form or transmitted by any means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the
  product described in this document are for reference only. Upon actual use, therefore, please request
  that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard
  use and operation. Please pay careful attention to the peripheral conditions when designing circuits
  and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or
  otherwise dispose of the same, no express or implied right or license to practice or commercially
  exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

#### About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.

In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.

ROHM

Appendix1-Rev1.1